

**REMARKS**

In response to the election requirement in the Office Action of July 23, 2003, Applicant hereby elects without traverse the Species I, directed to a method for manufacturing a semiconductor device having the step of forming the barrier layer and the third semiconductor film utilize the third semiconductor film as a gettering site to reduce the metal element/crystallization promote material from the first semiconductor film. Claims 107-179 read on the elected species.

Claims 212-262 are canceled.

Examination on the merits is requested.

Respectfully submitted,



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